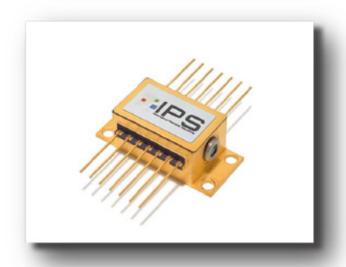
Multimode Open Beam Butterfly Package





Applications

This laser package is designed for OEM Integration and is ideal for:

- Hand-held Raman Spectroscopy
- Solid State Laser Pumping
- Laser Speckle Contrast Imaging
- Laser Illumination

Innovative Photonic Solutions' proprietary multimode wavelength stabilized laser diode features high output power with ultra-narrow spectral bandwidth and a collimated output beam. Designed to replace expensive DFB, DBR, fiber, and external cavity lasers, the multimode Spectrum Stabilized Laser offers superior wavelength stability over time, temperature, and vibration, and is manufactured to meet the most demanding wavelength requirements. The laser's stabilized peak wavelength remains "locked" regardless of case temp. (15 to 45°C). Devices can be spectrally tailored to suit application needs and offer side mode suppression ratios (SMSRs) better than 40 dB, thereby providing extremely high signal-tonoise ratio.

Key Features

- High Power Open Beam Multimode Output Power
- Ultra-Narrow Spectral Bandwidth (< 0.1 nm FWHM, 0.07 nm typical).
- Stabilized Output Spectrum (< 0.007 nm/°C)
- Low Power consumption
- 40 dB SMSR Typical
- 70 dB SMSR available upon request with additional filter
- "Ultratrack" Linear Tracking Photodiode

Standard Wavelengths

 638nm
 785nm
 860nm

 660nm
 808nm
 976nm

 680nm
 830nm
 1064 nm

Specifications

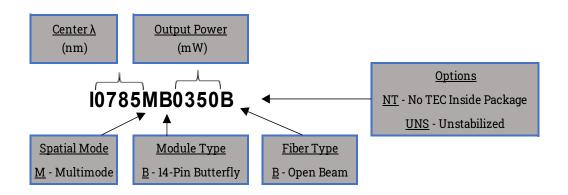


Wavelength Tolerance	+/- 0.5 nm	
Spectral Linewidth	<0.1nm (0.08nm typical)	
Wavelength Stability Range	15 - 45 °C	
SMSR	35 - 45 dB	
Power Stability	1% typical	
Polarization Extinction (PER)	>17dB, 20dB Typical	
Spatial Profile	TEM00	
Beam Exit Angle	< 3 degrees	
Beam Ellipticity	10:1	
Horizontal Beam Divergence	10 mrad Typ., 20 mrad Max	
Vertical Beam Divergence	2 mrad Typ., 5 mrad Max	

λ (nm)	Output Power (mW)	Base Part Number	Max Current Voltage
638	400*	I0638MB0400B	1000 mA, 3.3V
660	250	I0660MB0250B	1000 mA, 3.3V
680	300	I0680MB0300B	1000 mA, 3.3V
	350	I0785MB0350B	1000 mA, 2.3V
785	600	10785MB0600B	1350 mA, 2.3V
	800	10785MB0800B	1500 mA, 2.3V
	350	I0808MB0350B	1000 mA, 3.3V
808	600	10808MB0600B	1350 mA, 2.3V
	800	10808MB0800B	1500 mA, 2.3V
	350	10830MB0350B	1000 mA, 2.3V
830	600	10830MB0600B	1350 mA, 2.3V
	800	10830MB0800B	1500 mA, 2.3V
860	350	I0860MB0350B	1000 mA, 2.3V
	500	I0860MB0500B	1350 mA, 2.3V
976	800	10976MB0800B	1500 mA, 2.3V
1064	600	I1064MB0600B	1350 mA, 2.3V
	800	I1064MB0800B	1500 mA, 2.3V

^{*}Reduced wavelength stability range

Part Schema



Selected Data

TEC Current Limit	3.2 A
TEC Voltage Limit	5.8 V
Photodiode Current	30μΑ
Integral Thermistor	Betatherm 10K3CG3

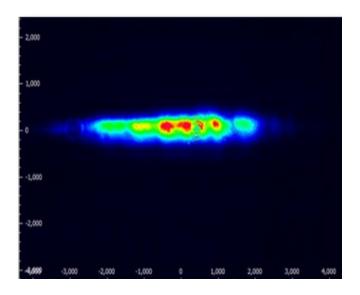
<dfb-ld analys<="" th=""><th></th><th>-3.0dB WD :</th><th>0.083nm</th><th>A:MAX HLD ∕BL</th></dfb-ld>		-3.0dB WD :	0.083nm	A:MAX HLD ∕BL
			-0.724nm	B:MIN HLD /BL
PK WL: 784.7			7.57dBm	C:WRITE ∠DSF
10.0dB/D	RES:0.01n	m SENS:MID	AUG:	1 SMPL:AUTO
27.6				
		on .		
7.6REF		X		†
dBm		1		
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-52.4				
780.00nm		785.00r	nm 1.00nn	n∕D 790.00nr

Typical 785nm SS Laser Spectrum

Custom Capability

- Custom wavelengths available upon request.
- External TEC (e.g. No TEC inside of package optional)





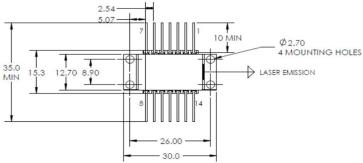
Typical 785nm Beam Quality

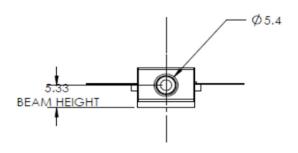
Electrical Specs

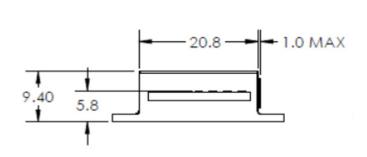
Pin 1	TEC+
Pin 2	Thermistor (10kOhm @25°C
Pin 3	PD Anode
Pin 4	PD Cathode
Pin 5	Thermistor
Pin 6-8	NC
Pin 9	Laser Cathode (-)
Pin 10	Laser Anode (+)
Pin 11	Laser Cathode (-)
Pin 12	NC
Pin 13	Case Ground
Pin 14	TEC -

Mechanical Drawings









OEM Laser Product: This laser module is designed for use as a component (or replacement) part and is thereby exempt from 21 CFR1040.10 and 1040.11 provisions.

Operational Notes

- 1. 14-pin BF should be mounted on a heat sink with a thermal compound (thermal grease).
- 2. Take care not to over-tighten screws when mounting. This can bend the BF package causing damage and hindering performance and is not covered under warranty.
- 3. Laser and TEC driver circuitry should be configured in a manner to prevent power /current / voltage surges and spikes.
- 4. IPS recommends not grounding anode and cathode as this can cause ground loops.
- 5. Laser and TEC driver circuitry should be configured in a manner to prevent power /current / voltage surges and spikes.
- 6. MM Open beam diodes will give beam ellipticity ~10:1 with hot spots and cool spots. If a more homogenous circularized beam is required, IPS recommends using a MM fiber coupled diode with a collimator.

Innovative Photonic Solutions, Inc.

313 Enterprise Drive Plainsboro, NJ 08536

Phone: (732) 230-1601

sales@ipslasers.com www.ipslasers.com









